

# 查询"CR12CM-12A"供应商 CR12CM-12A

# **Thyristor**

Medium Power Use

REJ03G0350-0200 Rev.2.00 Nov 30, 2007

### **Features**

I<sub>T (AV)</sub>: 12 A
 V<sub>DRM</sub>: 600 V
 I<sub>GT</sub>: 30 mA

Non-Insulated Type

Planar Passivation Type

## **Outline**

RENESAS Package code: PRSS0004AA-A (Package name: TO-220)



2, 4

- 1. Cathode
- 2. Anode
- 3. Gate
- 4. Anode

## **Applications**

Switching mode power supply, regulator for autocycle, motor control, heater control, and other general purpose control applications

## **Maximum Ratings**

Parameter	Symbol	Voltage class	Unit	
Faranietei	Symbol	12	Ollit	
Repetitive peak reverse voltage	V <sub>RRM</sub>	600	V	
Non-repetitive peak reverse voltage	V <sub>RSM</sub>	720	V	
DC reverse voltage	V <sub>R (DC)</sub>	480	V	
Repetitive peak off-state voltage	$V_{DRM}$	600	V	
DC off-state voltage	V <sub>D (DC)</sub>	480	V	

查询"CRPazameter <sub>2A</sub> "供应商	Symbol	Ratings	Unit	Conditions
RMS on-state current	I <sub>T (RMS)</sub>	18.8	Α	
Average on-state current	I <sub>T (AV)</sub>	12	Α	Commercial frequency, sine half wave 180° conduction, Tc = 91°C <sup>Note2</sup>
Surge on-state current	I <sub>TSM</sub>	360	Α	60Hz sine half wave 1 full cycle, peak value, non-repetitive
I <sup>2</sup> t for fusing	l <sup>2</sup> t	544	A <sup>2</sup> s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	$P_{GM}$	5	W	
Average gate power dissipation	P <sub>G (AV)</sub>	0.5	W	
Peak gate forward voltage	$V_{FGM}$	6	V	
Peak gate reverse voltage	$V_{RGM}$	10	V	
Peak gate forward current	I <sub>FGM</sub>	2	Α	
Junction temperature	Tj	- 40 to +125	°C	
Storage temperature	Tstg	- 40 to +125	°C	
Mass		2.0	g	Typical value

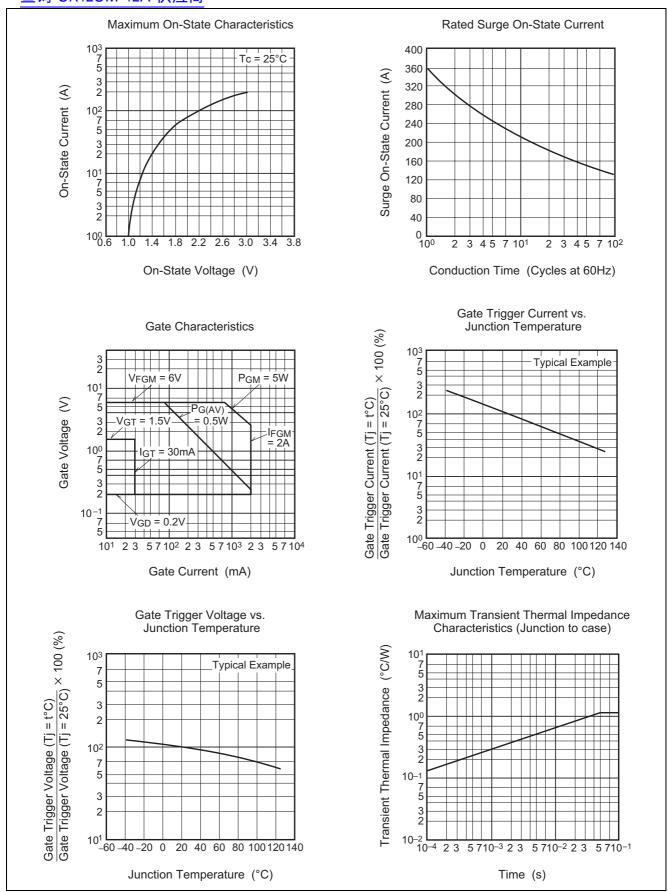
# **Electrical Characteristics**

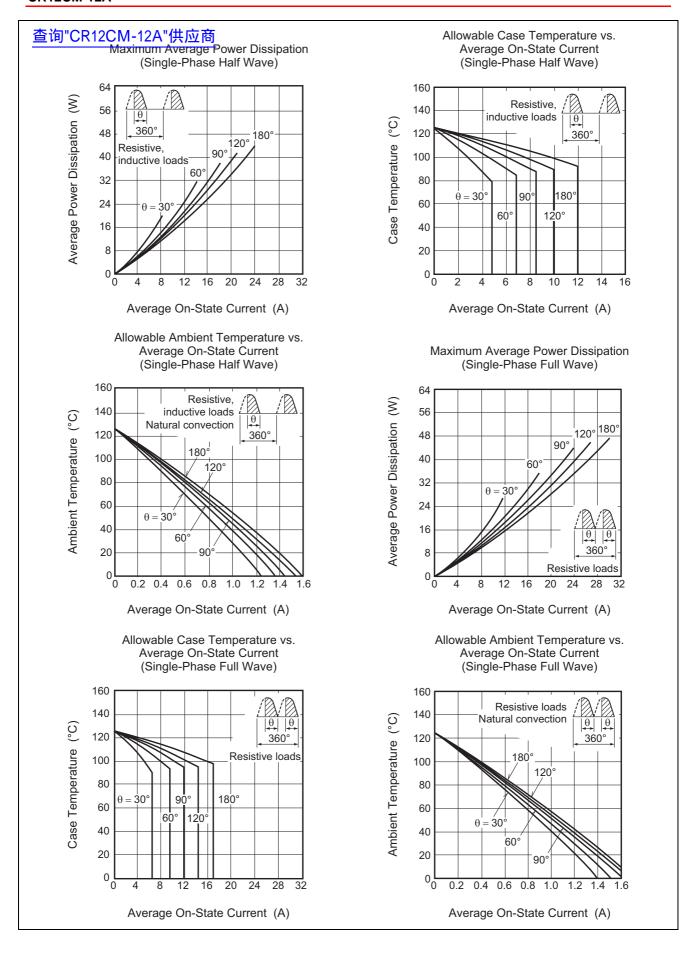
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak reverse current	$I_{RRM}$	_	_	2.0	mA	Tj = 125°C, V <sub>RRM</sub> applied
Repetitive peak off-state current	$I_{DRM}$	_	_	2.0	mA	Tj = 125°C, V <sub>DRM</sub> applied
On-state voltage	$V_{TM}$	_	_	1.6	V	$Tc = 25^{\circ}C$ , $I_{TM} = 40$ A,
						instantaneous value
Gate trigger voltage	$V_{GT}$	_	_	1.5	V	$Tj = 25$ °C, $V_D = 6 V$ , $I_T = 1 A$
Gate non-trigger voltage	$V_{GD}$	0.2	_	_	V	$Tj = 125$ °C, $V_D = 1/2 V_{DRM}$
Gate trigger current	I <sub>GT</sub>	_	_	30	mA	$Tj = 25$ °C, $V_D = 6$ V, $I_T = 1$ A
Holding current	I <sub>H</sub>	_	15	_	mA	Tj = 25°C, V <sub>D</sub> = 12 V
Thermal resistance	R <sub>th (j-c)</sub>	_	_	1.2	°C/W	Junction to case <sup>Note1 Note2</sup>

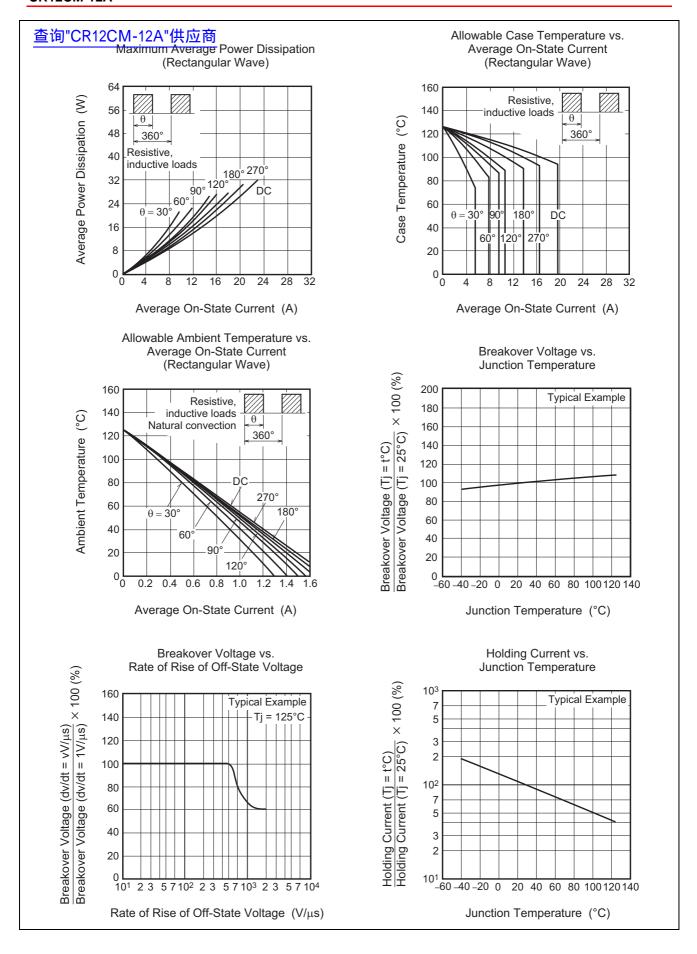
Notes: 1. The contact thermal resistance  $R_{th\ (c-f)}$  in case of greasing is 1.0°C/W.

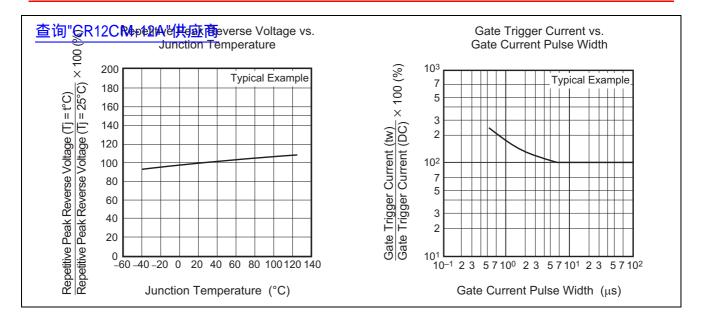
<sup>2.</sup> Case temperature is measured at anode tab 1.5 mm away from the molded case.

# Performance Curves 应商

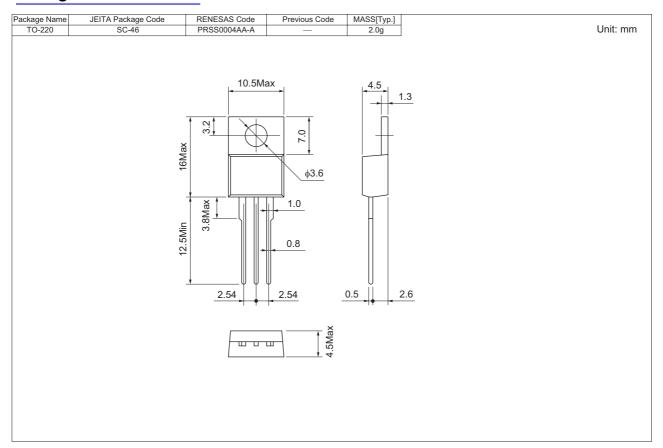








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## **Order Code**

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Vinyl sack	100	Type name	CR12CM-12A
Lead form	Plastic Magazine (Tube)	50	Type name – Lead forming code	CR12CM-12A-A8

Note: Please confirm the specification about the shipping in detail.

### Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

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## Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

**Renesas Technology Taiwan Co., Ltd.** 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510